Pb Free Plating Product



MUR3020PTD thru MUR3060PTD



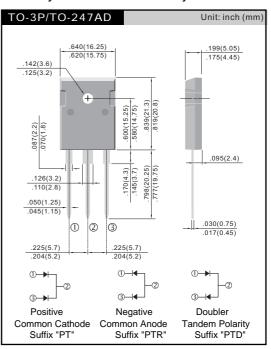
30.0 Ampere Dual Tandem Polarity Ultra Fast Recovery Rectifiers

Features

- ♦ Dual rectifier construction, positive center-tap
- Plastic package has Underwriters Laboratory Flammability Classification 94V0
- ♦ Glass passivated chip junctions
- ♦ Superfast recovery time, high voltage
- ♦ Low forward voltage, high current capability
- ♦ Low thermal resistance
- ♦ Low power loss, high efficiency
- High temperature soldering guaranteed: 260°C, 0.16"(4.06mm)from case for 10 seconds

Mechanical Data

- ♦ Cases: TO-3P/TO-247AD molded plastic
- Terminals: Pure tin plated, lead free solderable per MIL-STD-750. Method 2026
- ♦ Polarity: As marked
- ♦ Mounting position: Any
- ♦ Mounting torque: 10in-lbs. Max.
- ♦ Weight: 0.2 ounce, 5.6 gram approximately



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

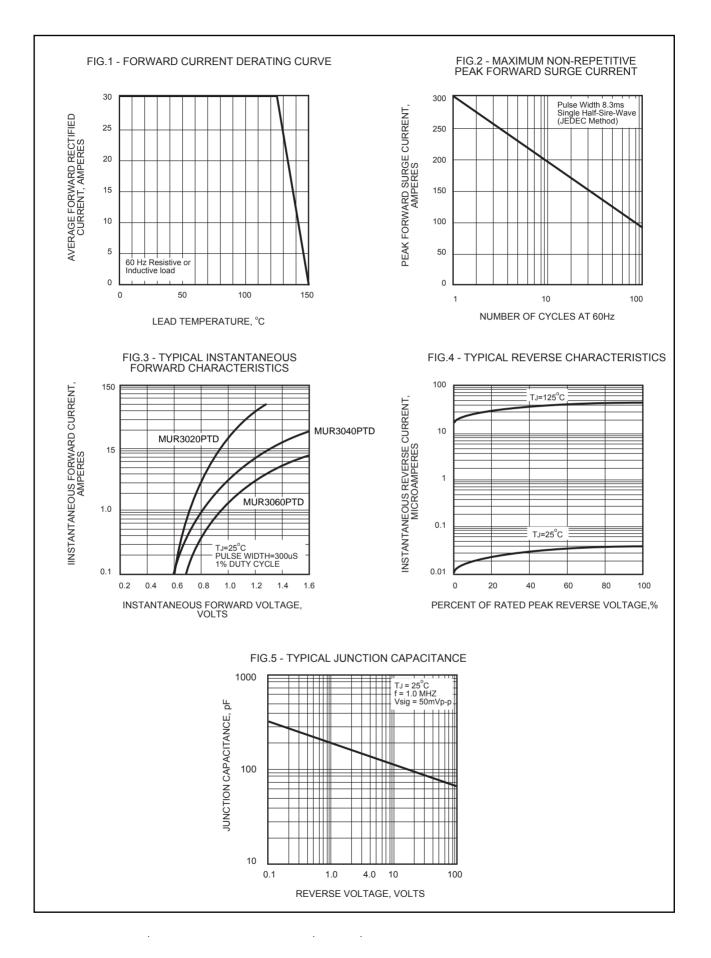
	SYMBOL	MUR3020PTR		MUR3060PT MUR3060PTR MUR3060PTD	
Maximum Recurrent Peak Reverse Voltage	Vrrm	200	400	600	V
Maximum RMS Voltage	Vrms	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=125°C	IF(AV)	30.0			А
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	300			A
Maximum Instantaneous Forward Voltage @ 15.0 A	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	lR	10 500			uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35			nS
Typical junction Capacitance (Note 2)	CJ	150			pF
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to +150			°C

NOTES : (1) Reverse recovery test conditions IF = 0.5A IR = 1.0A Irr = 0.25A.

(2) Thermal Resistance junction to terminal.

(3) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.





Rev.04/2014

Page 2/2